Diode Semiconductor Device - Page 1 of 1



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	nclosure Material:
G	Blass
C	overall Length:
0	.350 inches
T	erminal Length:
1	.000 inches
C	overall Diameter:
0	.145 inches
F	unction For Which Designed:
Z	ener diode
N	Iounting Method:
Т	erminal
F	eatures Provided:
F	lermetically sealed case
S	emiconductor Material:
S	ilicon
۷	oltage Rating In Volts Per Characteristic:
1	6.0 regulator voltage
۷	oltage Tolerance In Percent:
-{	5.0 to 5.0
C	current Rating Per Characteristic:
7	5.00 milliamperes voltage regulator diode current
P	ower Rating Per Characteristic:
5	.0 watts small-signal input power, common-collector absolute
N	laximum Operating Tempurature Per Measurement Point:
2	00.0 degrees celsius ambient air
Т	erminal Type And Quantity:
2	uninsulated wire lead
S	pecification Data:
8	0131-release 5750 professional/industrial association specification
S	helf Life:
Ν	l/a
ι	nit Of Measure:
C	emilitarization:
Ν	lo
F	iig:
	.110a0